[Memo]





2nd International Workshop on the

Sustainable Actions for "Year by Year Aging" under Reliability
Investigations in Photovoltaic Modules, 2017

SAYURI-PV 2017

Agenda

Date: November 11th – 12th, 2017

Venue: Ryukoku University, Seta Campus (Building 8)

1-5 Yokotani, Seta Oe-cho, Otsu, Shiga 520-2194, JAPAN http://www.ryukoku.ac.jp/english2/about/access/seta.html

Organizing Committee

Chair: Koji Matsubara

Yasuaki Ishikawa Atsushi Masuda Keiichiro Sakurai Tadanori Tanahashi Takahiro Wada Masaaki Yamamichi

Program Committee

Chair: Yasuaki Ishikawa

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Yuzuru Ueda Masaaki Yamamichi

Host

Research Center for Photovoltaics (RCPV) in National Institute of Advanced Industrial Science and Technology (AIST)

This workshop is held under the auspices of The Japan Electrical Manufacturers' Association (JEMA).

2nd International Workshop on the Sustainable Actions for "Year by Year Aging" under Reliability Investigations in Photovoltaic Modules, 2017 (SAYURI-PV 2017)

	nternational workshop on the Reliability Investigations in	Photovoltaic Modules, 2017 (SAYURI-PV 2017)								
[Day 1] November 11th										
9:30-	Opening Remarks	Yasuaki Ishikawa (NAIST)								
9:35-	Welcome	Koji Matsubara (AIST)								
9:40-	Welcome	Takahiro Wada (Ryukoku Univ.)								
Session		Chair: Yasuaki Ishikawa (NAIST)								
9:45-		ystalline silicon PV modules and a study of the energy rating standard for								
	PV modules under subtropical coastal climatic conditions									
	Tetsuyuki Ishii ¹ and Atsushi Masuda ² (¹ CRIEPI, ² AIST)									
Session		Chairs: Keiichiro Sakurai (AIST) and Yasuo Chiba (AIST)								
10:30-	. ,	ation? -Systematic study on various kinds of photovoltaic cells-								
	Atsushi Masuda¹ and Keisuke Ohdaira² (¹AIST, ²JAIST)									
11:00-										
	1 7 11 8	Toshimitsu Mochizuki (AIST)								
11:30-	Dry heat testing under light irradiation	• • •								
		Jiro Nishinaga and Hajime Shibata (AIST)								
11:50-	Lunch [Self Pay]									
	Cell (2)	Chair: Hajime Shibata (AIST) and Tadanori Tanahashi (AIST)								
13:00-		ninescence and current-voltage characteristics of photovoltaic modules								
	_	Yoshiteru Nitta², Kohji Masuda², Yasunori Uchida², and Tadashi Obayashi²								
	<u> </u>	(¹ Active Solar Innovation, ² JET)								
Session	III: Metallization	Chairs: Tadashi Obayashi (JET) and Tadanori Tanahashi (AIST)								
13:30-	Reliability of PERC solar modules fro									
13:30-	Reliability of PERC solar modules from Marwan Dhamrin, Shota									
13:30-		om cell metallization prospective								
13:30- 14:00-		om cell metallization prospective Suzuki, Morishita Naoya, Masahiro Nakahara, and Yoshiki Hasizume (Toyo Aluminium)								
	Marwan Dhamrin, Shota Degradation behavior of electrical con	om cell metallization prospective Suzuki, Morishita Naoya, Masahiro Nakahara, and Yoshiki Hasizume (Toyo Aluminium)								
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14:00- 14:30- 15:00- Session 15:30- 16:00- 16:45-	Marwan Dhamrin, Shota Degradation behavior of electrical contact Tanahash Corrosion mechanism on the interfacion cells by high-temperature high-humid Takeo Shimada ¹ , Kazuyoshi Yamad Break (30 min) IV: Polymer (1) The long-term life expectancy of 30 you Yasuaki Ishikawa ¹ , Hirotak The role of material interactions in PV Structural analysis of the degraded Etannihilation lifetime spectroscopy Hideaki Hagihara, Hiroaki Sa	Suzuki, Morishita Naoya, Masahiro Nakahara, and Yoshiki Hasizume (Toyo Aluminium) ntacts with acetic acid in c-Si PV cells i, Yukiko Hara, Norihiko Sakamoto, Hajime Shibata, and Atsushi Masuda (AIST) al glass layer between the metallization and the Si wafer of silicon solar ity test Taeko Semba ¹ , a¹, Katsuhiko Shirasawa², and Hidetaka Takato² (¹Namics, ²AIST) Chairs: Nick Bosco (NREL) and Atsushi Masuda (AIST) rears of silicon PV module analyzed by laser technique ta Iida², and Hidenari Nakahama² (¹NAIST, ²Nisshinbo Mechatronics) module reliability Gernot Oreski (PCCL) VA encapsulant in crystalline silicon photovoltaic module using positron								

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Reliability Investigations in Photovoltaic Modules, 2017 (SAYURI-PV 2017)									
[Day 2] November 12th									
Session	V: Polymer (2)	Chairs:	Gernot	Oreski (PC	CL), Takashi Ishiha	ra (Mitsubishi Electric),			
and Tadanori Tanahashi (AIST)									
9:00-	Study on reliability and long-term durability of bifacial module in terms of comparison of transparent backshee								
	type with glass type								
	Keita Arihara ¹ , Ryosuke Koyoshi ¹ , Yasuhiro Ishii ¹ , Masaru Kadowaki ¹ , Atsushi Nakahara ¹ , Hitoshi Nishikawa ¹ ,								
	Kinichi Ogawa ² , Yasuo Chiba ² , and Atsushi Masuda ² (¹Dai Nippon Printing								
9:20-	- Impact of backsheet quality on PERC module reliability								
	Yoshiki Hasizume, Marwan Dhamrin, Sakamoto Hiroyuki, and Maeda Daisuke								
						(Toyo Aluminium)			
9:50-	(PV module field failure in	Thailand)							
					Manit Seapan	(KMUTT)			
10:20-	Short-term and long-term field failures related to PV encapsulant in Japan								
					Tsuyoshi Shioda	(Mitsui Chemicals)			
10:50-	Quantifying adhesion in PV modules: A historical survey and degradation processes								
					Nick Bosco	(NREL)			
11:20-	Break (30 min)								
Session	VI: General Discussion	on	Chair:	Masaaki	Yamamichi (RTS C	Corp.)			
11:50-	JP efforts for PV-reliability	standardiza	tion						
					Isao Yoshida	(JEMA)			
12:05-	GENERAL DISCUSSION	N:							
	Theme: Feasibility of "service lifetime prediction" (based on "durability / aging of materials")								
	Moderators: Yasuaki Ishikawa, Tadanori Tanahashi, and Tsuyoshi Shiod								
12:50-	Closing Remarks				Yasuaki Ishikawa	(NAIST)			
13:00	Adjourn								

18:00- PVSEC-27: Welcome Reception at Lake Biwa Otsu Prince Hotel